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APPLICATION NO	. F	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/800,228		03/12/2004	Ben Wei Chen	3092P	3092P 8561	
29141	7590	10/06/2005		- EXAMINER		
		ROUP LLP	LAM, DAVID			
P O BOX 5 PALO AL		94303		ART UNIT PAPER NUMBER		
	ŕ			2827		
				DATE MAILED: 10/06/2003	5	

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)	an
	10/800,228	CHEN ET AL.	180
Office Action Summary	Examiner	Art Unit	
·	David Lam	2827	
The MAILING DATE of this communication a Period for Reply	appears on the cover sheet wit	h the correspondence addre	ss
A SHORTENED STATUTORY PERIOD FOR REF THE MAILING DATE OF THIS COMMUNICATIOI  - Extensions of time may be available under the provisions of 37 CFR after SIX (6) MONTHS from the mailing date of this communication.  - If the period for reply specified above is less than thirty (30) days, a ref - If NO period for reply is specified above, the maximum statutory perion.  - Failure to reply within the set or extended period for reply will, by sta Any reply received by the Office later than three months after the may earned patent term adjustment. See 37 CFR 1.704(b).	N. 1.136(a). In no event, however, may a re- reply within the statutory minimum of thirty od will apply and will expire SIX (6) MONT tute, cause the application to become ABA	ply be timely filed  (30) days will be considered timely.  HS from the mailing date of this comm  NDONED (35 U.S.C. § 133).	unication.
Status ·			
1)☐ Responsive to communication(s) filed on 25 2a)☐ This action is FINAL. 2b)☑ T 3)☐ Since this application is in condition for allow closed in accordance with the practice under	his action is non-final. wance except for formal matte		erits is
Disposition of Claims			
4) ⊠ Claim(s) 1-22 is/are pending in the application 4a) Of the above claim(s) is/are withd 5) □ Claim(s) is/are allowed. 6) ⊠ Claim(s) 1,2,4,8,11,13,14 and 22 is/are rejection claim(s) 1,5-7,9,10,12 and 15-21 is/are objection and claim(s) are subject to restriction and	cted.		
Application Papers			
9) The specification is objected to by the Exam  10) The drawing(s) filed on is/are: a) a  Applicant may not request that any objection to t  Replacement drawing sheet(s) including the corr  11) The oath or declaration is objected to by the	eccepted or b) objected to be the drawing(s) be held in abeyand rection is required if the drawing(s	ce. See 37 CFR 1.85(a). s) is objected to. See 37 CFR	
Priority under 35 U.S.C. § 119			
12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of:  1. Certified copies of the priority docume 2. Certified copies of the priority docume 3. Copies of the certified copies of the papplication from the International Burnets See the attached detailed Office action for a limit of the papplication from the International Burnets See the attached detailed Office action for a limit of the papplication from the International Burnets See the attached detailed Office action for a limit of the papplication from the International Burnets See the attached detailed Office action for a limit of the papplication from the International Burnets See the attached detailed Office action for a limit of the papplication from the International Burnets See the attached detailed Office action for a limit of the papplication from the International Burnets See the attached detailed Office action for a limit of the papplication from the International Burnets See the attached detailed Office action for a limit of the papplication from the International Burnets See the attached detailed Office action for a limit of the papplication from the International Burnets See the attached detailed Office action for a limit of the papplication from the International Burnets See the attached detailed Office action for a limit of the papplication from the International Burnets See the attached detailed Office action for a limit of the papplication from the International Burnets See the attached detailed Office action for a limit of the papplication from the International Burnets See the attached detailed Office action for a limit of the papplication from the International Burnets See the attached detailed Office action for a limit of the papplication from the International Burnets See the attached detailed Office action for a limit of the papplication from the International Burnets See the attached detailed Office action for the papplication from the Internation for a limit of the papplication from the Internation for the papp	ents have been received. ents have been received in Apriority documents have been reau (PCT Rule 17.2(a)).	oplication No received in this National Sta	age
Attachment(s)  1)  Votice of References Cited (PTO-892)  2)  Notice of Draftsperson's Patent Drawing Review (PTO-948)	Paper No(s)	ummary (PTO-413) /Mail Date	
3) Anformation Disclosure Statement(s) (PTO-1449 or PTO/SB/ Paper No(s)/Mail Date 10/25/04.		formal Patent Application (PTO-15	2)

Application/Control Number: 10/800,228

Art Unit: 2827

#### **DETAILED ACTION**

## Specification

- 1. The lengthy specification has not been checked to the extent necessary to determine the presence of all possible minor errors. Applicant's cooperation is requested in correcting any errors of which applicant may become aware in the specification.
- 2. The disclosure is objected to because of the following informalities: On page 22, line 1, transistor "175" should be change to -- 157 --. Appropriate correction is required.

## Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

This application currently names joint inventors. In considering patentability of the claims under 35 U.S.C. 103(a), the examiner presumes that the subject matter of the various claims was commonly owned at the time any inventions covered therein were made absent any evidence to the contrary. Applicant is advised of the obligation under 37 CFR 1.56 to point out the inventor and invention dates of each claim that was not commonly owned at the time a later invention was made in order for the examiner to consider the applicability of 35 U.S.C. 103(c) and potential 35 U.S.C. 102(e), (f) or (g) prior art under 35 U.S.C. 103(a).

Application/Control Number: 10/800,228

Art Unit: 2827

3. Claims 1-2, 4, 8, 11, 13-14, are rejected under 35 U.S.C. 102(b) as being anticipated by Chang (6,097,635).

Regarding to claims 1-2, 4, 8, 13-14, Chang discloses a multilevel flash cell architecture comprising: at least one flash cell (FMC); a plurality of reference generators (23, 24); a plurality of comparators (21,22) coupled to the flash cell via a sensing node and coupled to the plurality of plurality of reference generators; the plurality of the comparator for comparing a signal of the sensing node to a full spectrum (boundary) of reference voltage signals in parallel from the plurality of reference generators; and providing outputs; translation logic (25) coupled to the plurality of comparators for decoding the outputs to determine the state of the flash cell, wherein the most significant bit (MSB) and the least significant bit (LSB) of the state is provided from the translation logic; wherein the full spectrum of reference signals include boundary reference voltage between states and upper and lower target voltage within a state; wherein the at least on flash cell comprises a memory cell array with multilevel states per cell; wherein the translation logic detects when the cell is properly programmed (Won et al. cited to support know position of (. See Figs. 1-10; Cols. 1-5.

As of claim 11, Chang further discloses wherein each reference voltage generator generates a current for each boundary between 2<sup>n</sup> states for an upper limit and a lower limit for each state. See Figs. 1-10; Cols. 1-5.

## Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

Application/Control Number: 10/800,228

Art Unit: 2827

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

4. Claim 22 rejected under 35 U.S.C. 102(b) as anticipated by Chang (6,097,635) or, in the alternative, under 35 U.S.C. 103(a) as obvious over Won et al. (6,625,062).

As per above discussion, Chang discloses the claimed invention but not explicitly disclose wherein the flash memory device further comprising a plurality of memory cell strings each connected to x-y addressable word lines and bit lines.

However, Won et al. disclose a flash memory device comprising: a plurality of memory cell strings each connected to x-y addressable word lines and bit lines. See Fig. 3.

It would have been inherently included in Change's flash memory array, if not, it would have been obvious to one having ordinary skill in the modify Chang's memory array by utilizing Won et al.'s teach to form an array that include a plurality of memory cell strings each connected to x-y addressable word lines and bit lines to provide a reliable sensing within the flash memory device.

## Allowable Subject Matter

5. Claims 3, 5-7, 9-10, 12, 15-21 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

The following is a statement of reasons for the indication of allowable subject matter:

The prior art of record fails to teach the above multilevel flash cell architecture and wherein the translation logic detects underprogramming and overprogramming of a flash cell by comparing the sensing node to limits for each state.

Art Unit: 2827

### Conclusion .

6. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure.

- Kim et al. (6,717,848) disclose sensing circuit in a multilevel flash memory cell.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to David Lam whose telephone number is 571-272-1782. The examiner can normally be reached on 6:00-4:30.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Hoai Ho can be reached on 571-272-1777. The fax phone numbers for the organization where this application or proceeding is assigned is (571) 272-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

D. Lam

September 29, 2005

DAVID LAM RIMARY EXAMINER